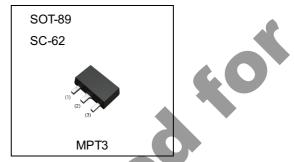


Middle Power Transistors (50V / 3A)

Parameter	Value	
V _{CEO}	50V	
IC	3A	

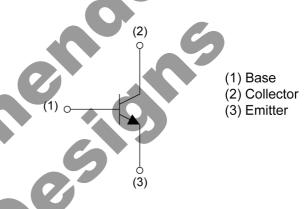
Outline



Features

- 1)Low saturation voltage, typically $V_{CE(sat)}$ =350mV(Max.) (I_C/I_B =1A/50mA)
- 2)High speed switching

•Inner circuit



Application

LOW FREQUENCY AMPLIFIER, HIGH SPEED SWITCHING

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SCR533P	SOT-89 (MPT3)	4540	T100	180	12	1000	NM

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit	
Collector-base voltage	V_{CBO}	50	V	
Collector-emitter voltage	V _{CEO}	V _{CEO} 50		
Emitter-base voltage	V _{EBO}	6	V	
Collector ourrent	Ic	3	Α	
Collector current		6	Α	
Down discipation	P _D *2	0.5	W	
Power dissipation	P _D *3	2.0	W	
Junction temperature	T _j	150	သိ	
Range of storage temperature	T _{stg}	-55 to +150	°C	

• Electrical characteristics ($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values		Linit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	Ι _C = 100μΑ	50		-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = 100μA	6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	-	ı	1.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	-	•	1.0	μA
Collector-emitter saturation voltage	V _{CE(sat)} *4	$I_C = 1A$, $I_B = 50 \text{mA}$	-	130	350	mV
DC current gain	h _{FE}	$V_{CE} = 3V$, $I_C = 50$ mA	180	-	450	-
Transition frequency	f _T *4	$V_{CE} = 10V, I_{E} = -500 \text{mA},$ f = 100MHz	-	320	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0A,$ f = 1MHz	-	13	-	pF
Turn-On time	t _{on}	I _C = 1.5A, I _{B1} = 150mA,	-	50	-	ns
Storage time	t _{stg}	$I_{B2} = -150 \text{mA},$ $V_{CC} \approx 10 \text{V},$	-	450	-	ns
Fall time	t _f	$R_L = 6.8\Omega$ See test circuit	-	80	-	ns

^{*1} Pw=10ms, Single Pulse

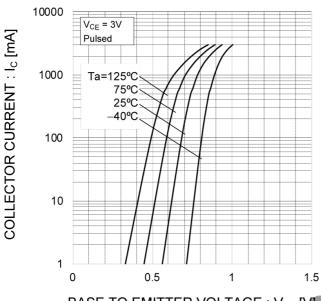
^{*2} Each terminal mounted on a reference land.

^{*3} Mounted on a ceramic board.(40×40×0.7mm)

^{*4} Pulsed

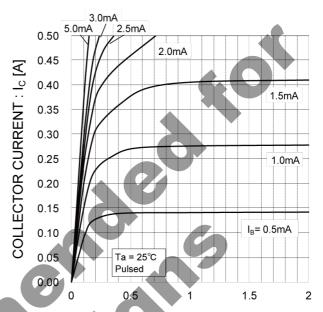
● Electrical characteristic curves(T_a = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE: VBE [V]

Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Fig.3 DC Current Gain vs. Collector Current (I)

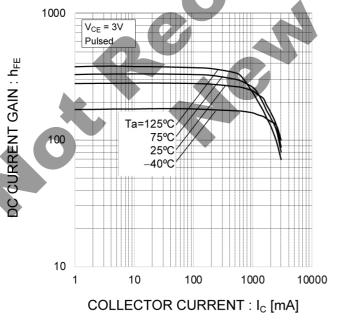
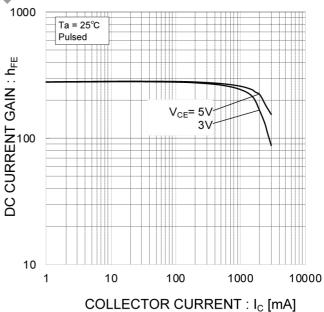


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

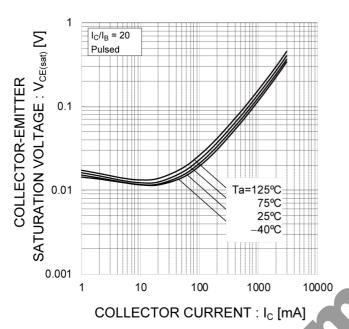


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

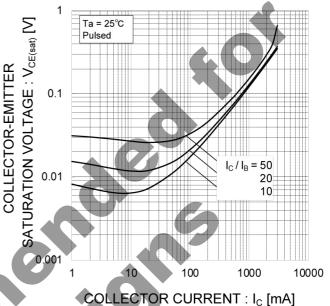


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

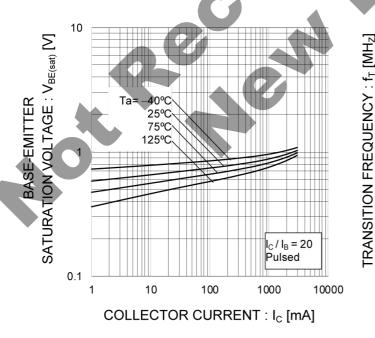
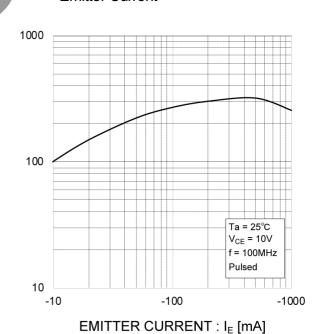


Fig.8 Gain Bandwidth Product vs.
Emitter Current



● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter Input Capacitance vs.
Emitter-Base Voltage
Collector Output Capacitance vs.
Collector-Base Voltage

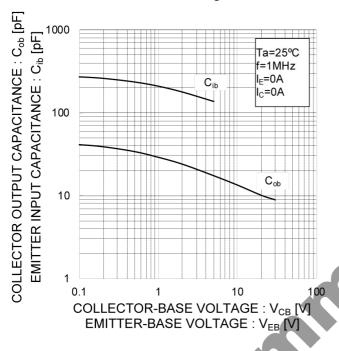
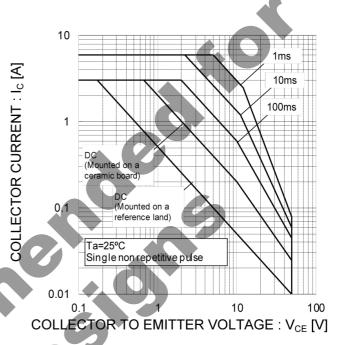
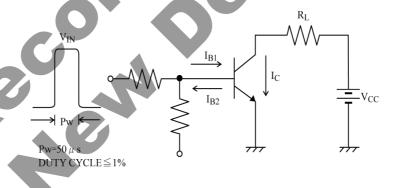
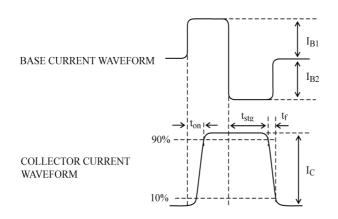


Fig.10 Safe Operating Area

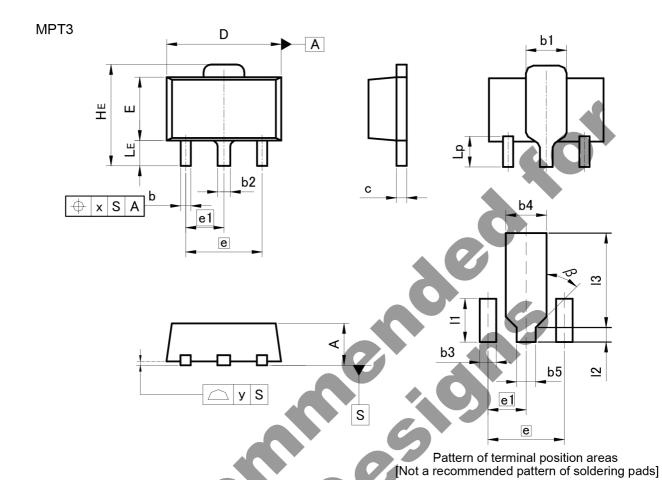


SWITCHING TIME TEST CIRCUIT





Dimensions



DIM	MILIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.5	50	0.0	0.059	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
х	_	0.15	-	0.006	
У	_	0.10	_	0.004	

	MIIIM	ETERS	INCHES		
DIM	MIN MAX		MIN MAX		
b3		0.65	INITIA	0.026	
b4	<u> </u>				
b5	_	1.70	_	0.067	
11	_	0.75	_	0.030	
11	_	1./1	_	0.067	
12	-	0.58	-	0.023	
13	-	3.72	-	0.146	
i R	45°		45	0	

Dimension in mm/inches

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